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A Self Bias-flip Piezoelectric Energy Harvester Array without External Energy Reservoirs achieving 488% Improvement with 4-Ratio Switched-PEH DC-DC Converter

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With the advent of the Internet-of-Things (IoT) era, sensor nodes are required in almost all fields to achieve a better interaction between humans and the environment. Piezoelectric energy harvester (PEH), which exhibits an equivalent electrical model of an AC current source I_P in parallel with the inherent capacitor C_P , is a promising technology to resolve the energy problem of such sensor nodes. Recently, inductor-based rectifiers, capacitor-based rectifiers and hybrid rectifiers have been proposed to improve the energy extraction efficiency of PEH devices [1-5]. However, these structures all require the aid of additional capacitors or inductors to achieve bias-flip operation, as illustrated in Fig. 1. These extra passive devices are typically large, which can be a major bottleneck in system-volume-constrained applications such as MEMS [4]. In response to the above problem, this work proposes a novel 8-phase self bias-flip PEH interface with charge recycling and reusing (SBFRR). By using the C_P of 4 PEHs as flipping capacitors, this scheme achieves a high voltage flipping efficiency without using extra energy reservoirs. The 4 C_P can also serve as flying capacitors to achieve switched-PEH DC-DC (SPDC) conversion for MPPT, while maintaining a MOPIR of $>3.5\times$ with a PEH input voltage (V_P) from 0.78V to 4.9V.

Fig. 1 shows the proposed system using 4 PEHs, with three operating states including energy harvesting (EH), zero-crossing (ZC), and MPPT. During the EH state, the 4 PEHs work as normal harvesters and flipping capacitors alternately to extract vibration power. The ZC state consists of the recycle phase (PH_{RYC}), bias-flip phase (PH_{BF1-5}), reuse phase (PH_{RUS}) and rebalance phase (PH_{RB}). For illustration purpose, we assign PEH_{<1,2>} serve as conventional PEHs, and configure PEH_{<3,4>} as flipping capacitors. Starting from PH_{RYC}, PEH_{<3,4>} transfer half of the charge to C_{RECT} , followed by PH_{BF1} where the residual charge is completely discharged. The charge on PEH_{<1,2>} is gradually flipped in 3 steps from PH_{BF2} to PH_{BF4}, and then finally cleared in PH_{BF5}. To improve the energy extraction efficiency, the previously recovered charge at C_{RECT} is re-injected to PEH_{<1,2>} in PH_{RUS}, and the PEH voltage is then equalized in PH_{RB}. As the duration of the ZC state is about 80 μ s which accounts for only 1.6% of half the excitation cycle, PEH_{<3,4>} can be regarded as flipping capacitors during this period without sacrificing the energy harvesting efficiency. The involvement of the charge recycle and reuse phases (i.e., PH_{RYC} and PH_{RUS}) can also theoretically improve the MOPIR from 3.88 $\times$ to 5.13 $\times$.

Fig. 2 presents the operation of the proposed SPDC at EH state, where the 4 PEHs serve as flying capacitors for DC-DC conversion to extend the input power range. It is composed of 3 phases (PHEH0~PHEH2). During PHEH0, the 4 PEHs transfer charges to C_{RECT} through the active rectifier (AR), which is also responsible for zero-crossing detection and I_P polarity determination. At PHEH1, the PEH array and C_{RECT} together form a SPDC to deliver charge to the load, with a total 4 possible voltage conversion ratios (VCRs) through SPDC reconfiguration. To prevent error during zero-crossing detection at PHEH0, the voltages on PEH_{<1,4>} and C_{RECT} are rebalanced in PHEH2. This can also prevent the PEH from deviating from the MPP. In this work, the time duration ratio of PHEH0~PHEH2 is 3:1:2. The proposed system typically transits between the ZC and EH states. Upon the triggering of the external signal V_{MODE} , the system will temporarily switch to the MPPT state. As observed in the system diagram, the AR outputs $V_{CP<1,2>}$ serve to generate the corresponding ZC/EH pulse sequences to control the analog switch array. Dual supply domains are employed in order to reduce power consumption. The chip occupies an active area of $\sim 0.7\text{mm}^2$ as illustrated in the die micrograph.

Fig. 3 depicts the schematics of the key circuit modules. The analog switches are sized according to the path current to increase the power density. In order to prevent oscillation of $V_{CP<1,2>}$ as induced by the comparator offsets, the proposed anti-oscillation technique

ensures that only one transition of $V_{CP<1,2>}$ can occur per half excitation cycle. $V_{CP<1,2>}$ will be sampled at 2/3 the duration of PHEH0 to obtain $V_{ZC<1,2>}$, which is then processed by the ZC and EH sequencer to generate the required control sequence. The digital sequence generation blocks operate at 1.6V, and level shifters (LS) are employed to convert the 4.8-V supply for driving the switch array. Each LS only consumes 0.53pJ per cycle.

We explore the fractional open-circuit voltage (FVOC) method for MPPT, and employ a ratioed peak detector to prevent detection error or overshoot. Here, D_1 is responsible for rectifying the PEH output, and R_1 for reducing the impedance across the PEH terminals. The detected peak voltage V_{RPV} is scaled to about 0.5 V_P . The 3-bit comparator outputs pulses according to V_{RPV} for triggering DFF₁ and DFF₂, with the results further processed by the encoder to configure the VCR and f_{OSC_SLOW} .

Fig. 4 shows the measured waveform across the PEH terminals with VCR=2 at an excitation frequency of 100Hz. During the ZC state, after 8 phases of SBFRR operation, the PEH voltage is flipped from [2.5V] to [1.5V], corresponding to a voltage flipping efficiency of 80%. At EH state, $V_{PEH<1,4>}$ is charged from the rebuilt voltage (V_{RBT}), with the clock signal (f_{ZCD_SAMPLE}) triggering the sampling of $V_{CP<1,2>}$. When $V_{PEH<1,4>}$ exceeds V_{RECT} , AR is turned on, and the system starts to operate among the EH phases (PHEH0~PHEH2). If $V_{PEH<1,4>}$ is lower than V_{RECT} , the system will reenter the ZC state, leading to a droop at V_{RECT} as observed in Fig. 4 as induced by the charge injection in the PH_{RYC} phase. This droop will be recovered in the PH_{RUS} phase due to the connection to C_{RECT} .

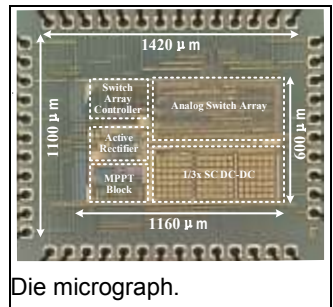
Fig. 5 presents the MPPT results, where the system automatically switches from VCR=2 to VCR=1, with the driving clock f_{OSC_SLOW} also adaptively updated. Fig. 5 also depicts the relationship between P_{RECT} versus V_{RECT} under different V_P , as well as P_{OUT} versus V_P under different VCR. The test results show that the energy loss caused by the vibration mismatches of four PEHs can be ignored. The measured MOPIR_{RECT} can be up to 4.98 $\times$ when $V_P \sim 2.3\text{V}$. The MOPIR is obtained by comparing the measured maximum output power with the calculated output power for an ideal full-bridge rectifier (with diode drop $V_D=0$). When VCR=1, the MOPIR of the system can reach 4.88 $\times$. As VCR increases, the MOPIR reduces due to the reduction of the zero-crossing accuracy. However, when VCR=4, the MOPIR can still reach 2.78 $\times$, which is a 39% improvement compared to the ideal switch-only rectifier. The entire system can maintain a MOPIR of $>3.5\times$ when V_P is from 0.78V to 4.9V. Fig. 6 shows the comparison of the proposed design with the state of the art. Compared to [4], this work achieves MPPT by using switched PEH converter while requesting a much smaller chip area. Compared to [1-3, 5], this work achieves the highest FoM without using external energy reservoirs, which is imperative to applications requiring an ultra-compact system volume.

Acknowledgments:

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Die micrograph.

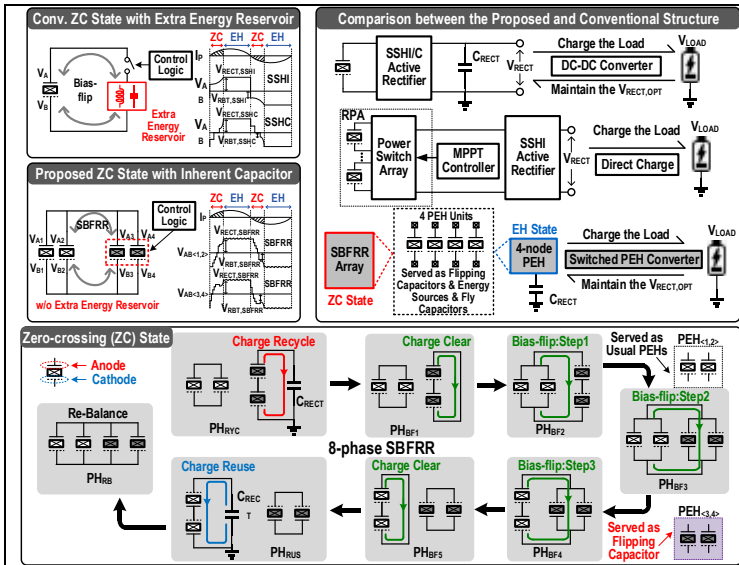


Fig. 1. Comparison of the conventional technique with the proposed scheme (top); and operation of the zero-crossing state (bottom).

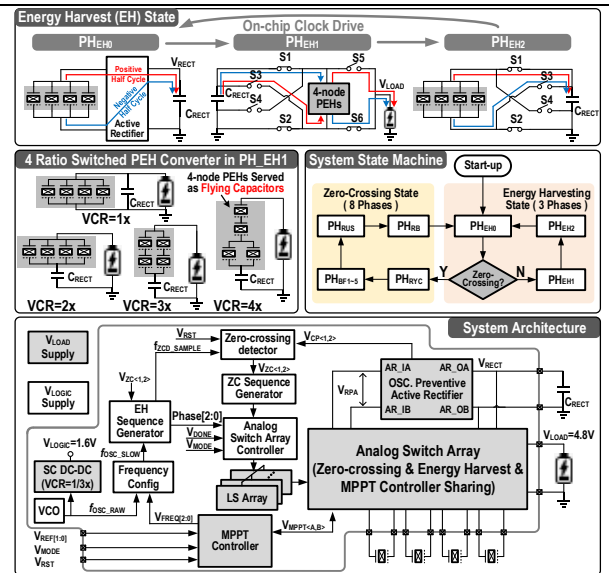


Fig. 2. Operation of the energy harvesting state (top); SPDC and system state machine; and the system architecture (bottom).

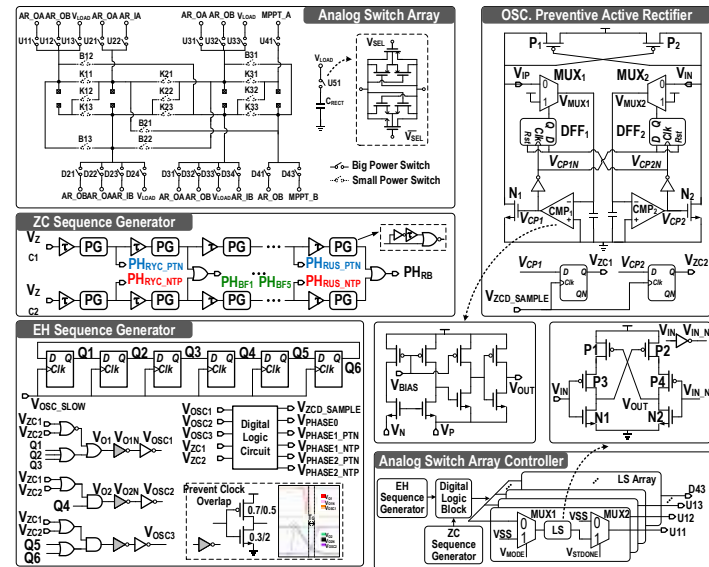


Fig. 3. Circuit implementation of switch array, oscillation preventive active rectifier and sequence generators.

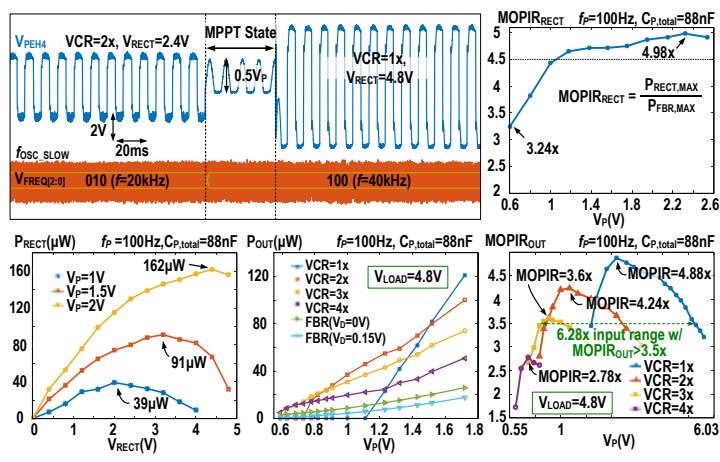


Fig. 5. Measured MPPT operation (top left); P_{RECT} vs. V_{RECT} at 1/1.5/2V V_P (bottom left); measured P_{OUT} vs. V_P under different VCR (bottom middle); measured MOPI_{RECT} and MOPI_{OUT} vs. V_P with 4 VCR (right).

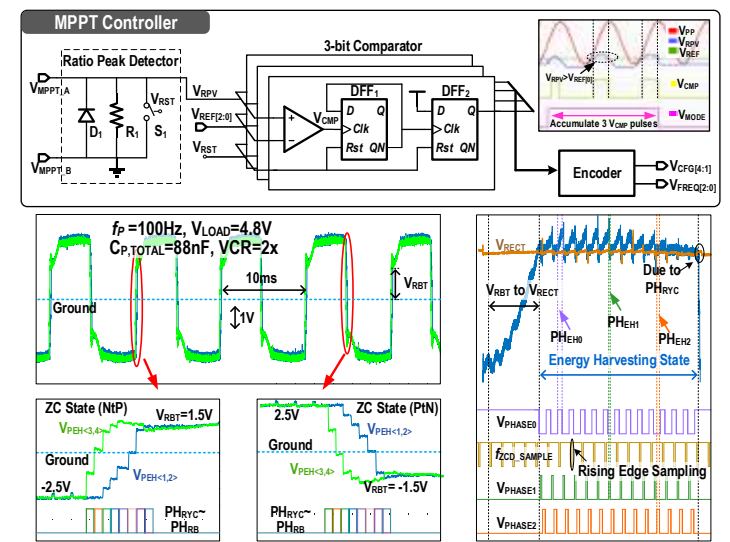


Fig. 4. MPPT controller (top); measured waveform of the V_{PEH} and zoomed-in zero-crossing state and energy harvesting state (bottom).

	JSSC'19 [1]	JSSC'20 [2]	ISSCC'19 [3]	JSSC'19 [4]	ISSCC'22 [5]	This Work
Technology	0.13 μ m	0.18 μ m	0.18 μ m	0.18 μ m	65nm	0.18 μ m
Technique	SSH1	SPFCR	SaS	SE-SSH	MSVR SECE	Self Bias-Flip
Passive Energy Reservoir for Bias-Flip	L=33 μ H	C_{TOTAL} =272nF	L=1mH C_{TOTAL} =10nF	C_{TOTAL} =4nF	L=22 μ H	None
Passive Energy Reservoir for DC-DC	N/A	C_{TOTAL} =272nF	L=1mH C_{TOTAL} =10nF	N/A	L=22 μ H	None
Normalized Volume VNOR*	1.3	1.3	11.15	1	1.29	1
Chip Size	0.53mm ²	0.2mm ²	0.47mm ²	3.9mm ²	3.11mm ²	0.7mm ²
Pin Adaptation	N/A	SC DC-DC	N/A	SECE	SECE	Switched PEH Converter
No. of Inputs	1	1	1	4	3	4
Piezoelectric Capacitor	22nF	22nF	8nF	1.94nF	N/A	88nF (22nF each)
Flipping Efficiency	0.88	0.84	N/A	0.85	N/A	0.8
MOPI*	3.66x	3.7x ~ 6.26x	3.96x	2.57x ~ 5.89x	3.2x	2.78x ~ 4.88x
FoM*	2.82	2.84 ~ 4.77	0.36	2.57 ~ 5.89	2.48	2.78 ~ 4.88
Conversion Ratio	N/A	1/3x, 2/3x, 1x, 2x	Continuous	N/A	Continuous	1x, 2x, 3x, 4x
Operating Freq.	432Hz	200Hz	85Hz	219Hz	N/A	100Hz

*VNOR = System Volumen / Chip Volumen

*MOPI = $P_{OUT} / P_{FBR,MAX}$

+FoM = MOPI / VNOR

Fig. 6. Performance summary and benchmark with prior art.